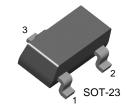


KST5401

High Voltage Transistor



1. Base 2. Emitter 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	-160	V
V _{CEO}	Collector-Emitter Voltage	-150	V
V_{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-500	mA
P _C	Collector Power Dissipation	350	mW
T _{STG}	Storage Temperature	150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C} = -100\mu A, I_{E} = 0$	-160		V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = -1.0mA, I _B =0	-150		V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = -10μA, I _C =0	-5		V
I _{CBO}	Collector Cut-off Current	V _{CB} = -100V, I _E =0		-50	nA
h _{FE}	DC Current Gain	V _{CE} = -5V, I _C = -1.0mA	50		
		$V_{CE} = -5V, I_{C} = -10mA$	60	240	
		V_{CE} = -5V, I_{C} = -50mA	50		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -10mA, I _B = -1.0mA		-0.2	V
		$I_C = -50 \text{mA}, I_B = -5 \text{mA}$		-0.5	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = -10mA, I _B = -1.0mA		-1.0	V
		I_C = -50mA, I_B = -5mA		-1.0	V
f _T	Current Gain Bandwidth Product	I _C = -10mA, V _{CE} = -10V	100	300	MHz
		f=100MHz			
C _{ob}	Output Capacitance	V _{CB} = -10V, I _E =0, f=1.0MHz		6.0	pF
NF	Noise Figure	V _{CE} = -5V, I _C = -200μA		8.0	dB
		R_S =10K Ω , f=10Hz to 15.7KHz			





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Typical Characteristics

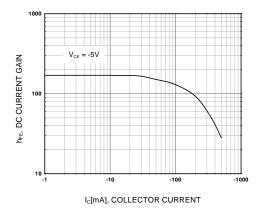


Figure 1. DC current Gain

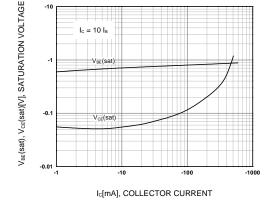


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

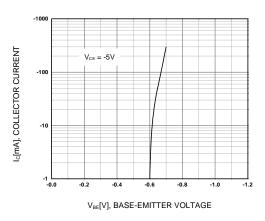


Figure 3. Base-Emitter On Voltage

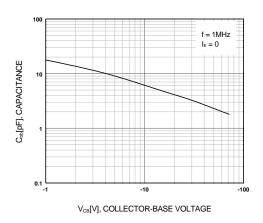


Figure 4. Output Capacitance

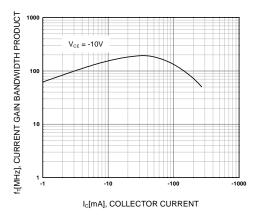
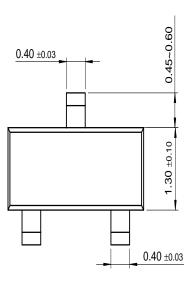


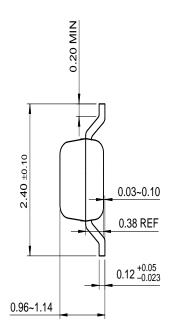
Figure 5. Current Gain Bandwidth Product

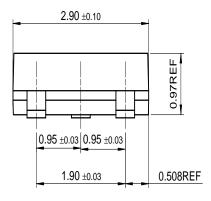
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Package Dimensions

SOT-23







Dimensions in Millimeters

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EnSigna™	I^2C^{TM}	OCX^{TM}	RapidConfigure™	UHC™
Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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